Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

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Plastic Infrared Emitting Diode

OP265, OP266 Series

(A, B, C, D, W)

Features:

- T-1 (3 mm) package style
- Choice of narrow or wide irradiance pattern
- Choice of dome or flat lens
- Mechanically and spectrally matched to other OPTEK devices
- Higher power output than GaAs at equivalent drive currents
- 890 nm diodes

Description:

Each device in the **OP265** and **OP266** series is a high intensity gallium arsenide infrared emitting diode (GaAlAs) that is molded in an IR transmissive clear epoxy package with either a dome or flat lens. Devices feature narrow and wide irradiance patterns and a variety of electrical characteristics. The small T-1 package style makes these devices ideal for space-limited applications.

OP265 devices conform to the OP505 and OP535 series devices. OP266 devices conform to OP506 series devices.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Applications:

- Space-limited applications
- Applications requiring coupling efficiency
- Battery-operated or voltage-limited applications

Ordering Information

Part Number	LED Peak Wavelength	Output Power (mW/cm^2) Min / Max	I_F (mA) Typ / Max	Total Beam Angle	Lead Length
OP265A	890 nm	2.70 / NA	20 / 50	18°	See page 2
OP265B		1.65 / 4.70			
OP265C		0.54 / 3.30			
OP265D		0.54 / NA			
OP265W		1.00 / NA		90°	
OP266A		2.70 / NA		18°	
OP266B		1.65 / 4.70			
OP266C		0.54 / 3.30			
OP266D		0.54 / NA			
OP266W		1.00 / NA		90°	

RoHS

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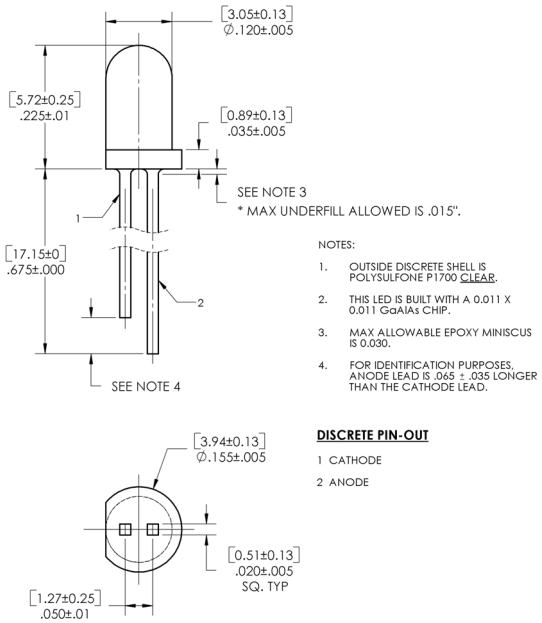
Plastic Infrared Emitting Diode

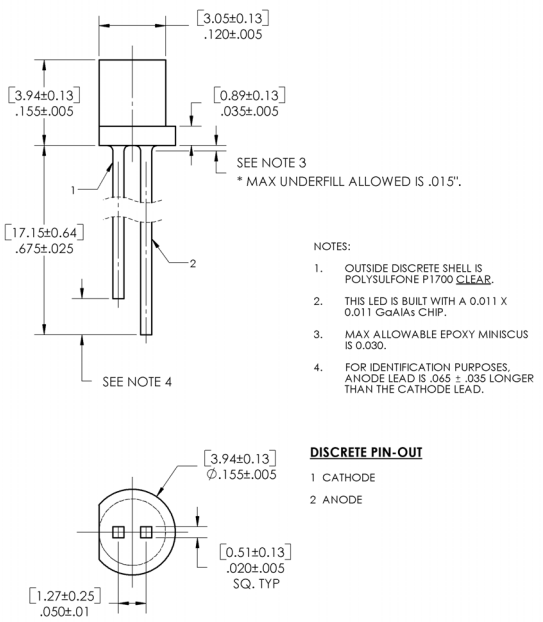
OP265, OP266 Series

(A, B, C, D, W)

OP265 (A, B, C, D)

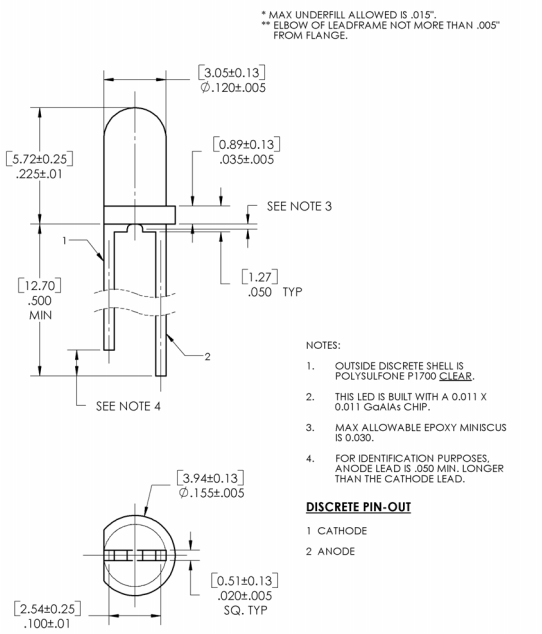


OP265W

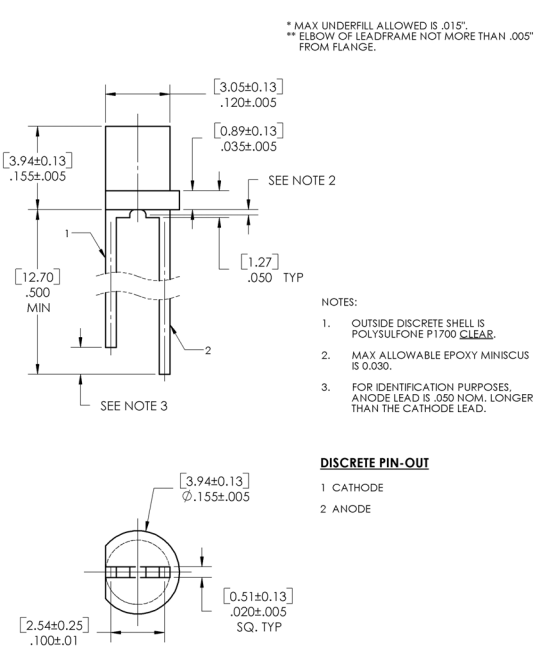


DIMENSIONS ARE IN: [MILLIMETERS] INCHES

OP266 (A, B, C, D)



OP266W



Pin #	LED
1	Cathode
2	Anode

CONTAINS POLYSULFONE

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.

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Plastic Infrared Emitting Diode

OP265, OP266 Series

(A, B, C, D, W)

Electrical Specifications

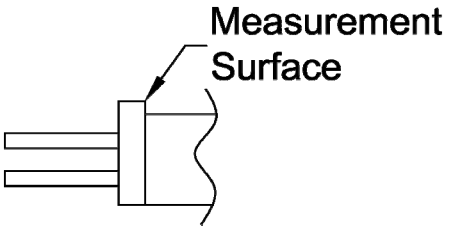
Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)	
Storage and Operating Temperature Range	-40° C to +100° C
Reverse Voltage	2.0 V
Continuous Forward Current	50 mA
Peak Forward Current (1 µs pulse width, 300 pps)	3.0 A
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C
Power Dissipation	100 mW(1)

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
$E_{E\ (APT)}$	Apertured Radiant Incidence OP265A, OP266A OP265B, OP266B OP265C, OP266C OP265D, OP266D	 2.70 1.65 0.54 0.54	 - - - -	 - 4.70 3.30 -	mW/cm²	I_F = 20 mA(2)
P_O	Radiant Power Output OP265, OP266 (A, B, C, D) OP265W, OP266W	 - 1.00	 - -	 - -	mW	I_F = 20 mA
V_F	Forward Voltage	-	-	1.80	V	I_F = 20 mA
I_R	Reverse Current	-	-	100	µA	V_R= 2 V
λ_P	Wavelength at Peak Emission	-	890	-	nm	I_F = 10 mA
B	Spectral Bandwidth between Half Power Points	-	80	-	nm	I_F = 10 mA
$\Delta\lambda_P/\Delta T$	Spectral Shift with Temperature OP265, OP266 (A, B, C, D) OP265W, OP266W	- -	±0.30 ±0.18	- -	nm/°C	I_F = Constant
θ_{HP}	Emission Angle at Half Power Points OP265, OP266 (A, B, C, D) OP265W, OP266W	- -	18 90	- -	Degree	I_F = 20 mA
t_r	Output Rise Time	-	500	-	ns	$I_{F(PK)}$=100 mA, PW=10 µs, D.C.=10.0%
t_f	Output Fall Time	-	250	-	ns	$I_{F(PK)}$=100 mA, PW=10 µs, D.C.=10.0%

Notes:

1. Derate linearly 1.33 mW/°C above 25°C
2. $E_{E(APT)}$ is a measurement of the average apertured rediant incidence ipon a sensing area 0.081" (2.06 mm) in diameter, perpendicular to and centered on the mechanical axis of the lens, and 0.590" (14.99 mm) from the measurement surface. $E_{E(APT)}$ is not necessarily uniform within the measured areas.



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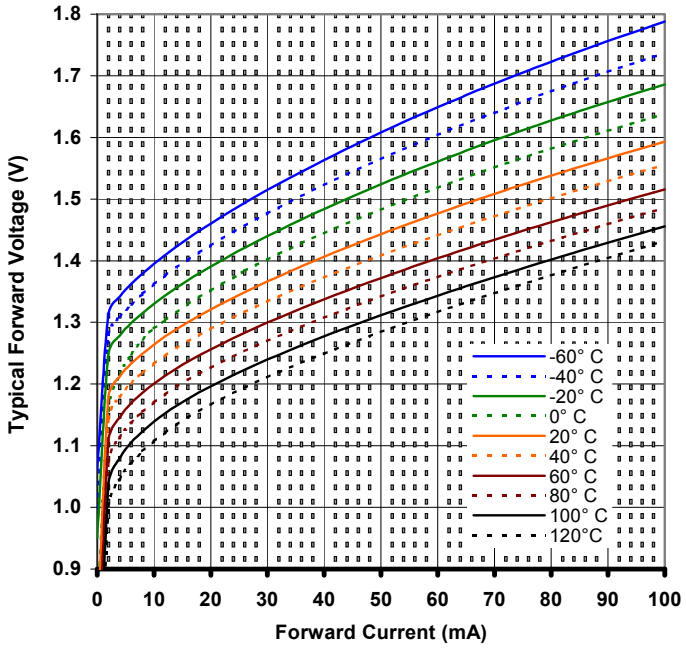
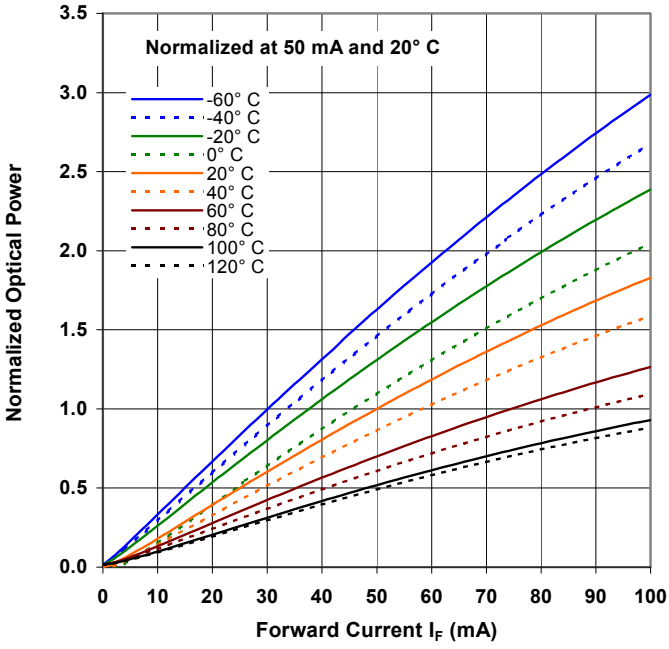
Performance

OP265, OP266 (A, B, C, D, W)

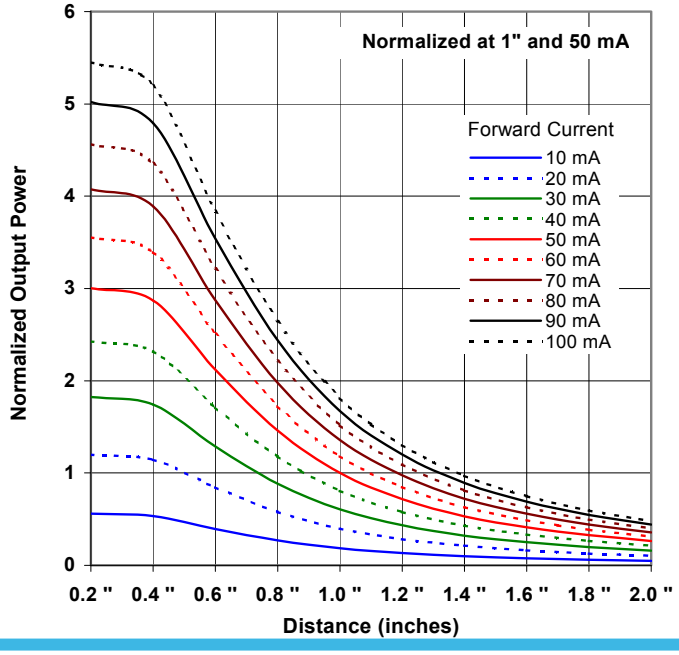
Forward Voltage vs Forward Current vs Temperature



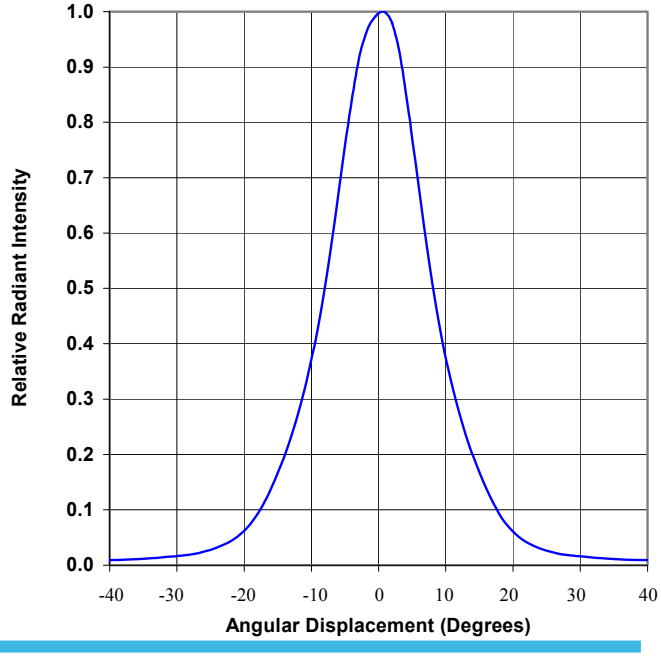
Optical Power vs I_F vs Temperature



Distance vs Output Power vs Forward Current



Relative Radiant Intensity vs. Angular Displacement



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